

V V <sub>RSM</sub> V <sub>RRM</sub>	I <sub>FRMS</sub> (maximum values for continuous operation)			
	260 A			
	I <sub>FAV</sub> (sin. 180; T <sub>case</sub> = 85 °C)			
	160 A	168 A		
t <sub>rr</sub> = 500 ns		t <sub>rr</sub> = 800 ns		
V				
800	SKN 135 F 08	SKR 135 F 08		
1000	SKN 136 F 08	SKR 136 F 08		
1200	SKN 135 F 10	SKR 135 F 10		
1400	SKN 136 F 10	SKR 136 F 10		
1500	SKN 135 F 12	SKR 135 F 12	SKN 140 F 12	SKR 140 F 12
1700	SKN 136 F 12	SKR 136 F 12	SKN 141 F 12	SKR 141 F 12
			SKN 140 F 14	SKR 140 F 14
			SKN 141 F 14	SKR 141 F 14
			SKN 140 F 15	SKR 140 F 15
			SKN 141 F 15	SKR 141 F 15
			SKN 141 F 17	SKR 141 F 17

## Fast Recovery Rectifier Diodes

SKN 135 F SKR 135 F  
 SKN 136 F SKR 136 F  
 SKN 140 F SKR 140 F  
 SKN 141 F SKR 141 F



Symbol	Conditions	SKN 135 F SKR 135 F SKN 136 F SKR 136 F	SKN 140 F SKR 140 F SKN 141 F SKR 141 F	Units
I <sub>FAV</sub>	sin. 180; T <sub>case</sub> = 85 °C; 1000 Hz T <sub>case</sub> = 100 °C; 1000 Hz	160	168	A
		135	140	A
	sin. 180/T <sub>amb</sub> = 45 °C; K 1,1	54 / 52	55 / 53,5	A
i <sup>2</sup> t	rec. 120 P 1/200	97 / 93	100 / 96	A
	K 0,55	80 / 76	82 / 78	A
	T <sub>amb</sub> = 35 °C; P1/120F	136 / 130	141 / 134	A
	K1,1F	110 / 105	114 / 109	A
I <sub>FSM</sub>	T <sub>vj</sub> = 25 °C; 10 ms	2500		A
	T <sub>vj</sub> = 150 °C; 10 ms	2100		A
	T <sub>vj</sub> = 25 °C; 8,3 ... 10 ms	31000		A <sup>2</sup> s
	T <sub>vj</sub> = 150 °C; 8,3 ... 10 ms	22000		A <sup>2</sup> s
Q <sub>rr</sub>	T <sub>vj</sub> = 150 °C I <sub>F</sub> = 100 A	50	90	μC
I <sub>RM</sub>	V <sub>R</sub> = 400 V I <sub>F</sub> = 300 A	75	135	μC
	- dI <sub>F</sub> /dt = 10 A/μs I <sub>F</sub> = 100 A	53	90	A
		69	115	A
I <sub>R</sub>	T <sub>vj</sub> = 25 °C; V <sub>R</sub> = V <sub>RRM</sub>	1		mA
	T <sub>vj</sub> = 150 °C; V <sub>R</sub> = V <sub>RRM</sub>	100		mA
t <sub>rr</sub>	T <sub>vj</sub> = 25 °C I <sub>F</sub> = I <sub>R</sub> = 1 A	max. 500	max. 800	ns
	T <sub>vj</sub> = 150 °C typ. 1	typ. 1	typ. 1,6	μs
V <sub>F</sub>	T <sub>vj</sub> = 25 °C; I <sub>F</sub> = 300 A	max. 1,95	max. 1,80	V
V <sub>(TO)</sub>	T <sub>vj</sub> = 150 °C	1,1	1,1	V
r <sub>T</sub>	T <sub>vj</sub> = 150 °C	2,3	2	mΩ
R <sub>thjc</sub>		0,2		°C/W
R <sub>thch</sub>		0,08		°C/W
T <sub>vj</sub>		- 40 ... + 150		°C
T <sub>stg</sub>		- 55 ... + 150		°C
M	SI (US) units	10 (90 lb.in.)		Nm
a		5 · 9,81		m/s <sup>2</sup>
w	approx.	100		g
Case	135 F, 140 F	E 14		
	136 F, 141 F	E 31		

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

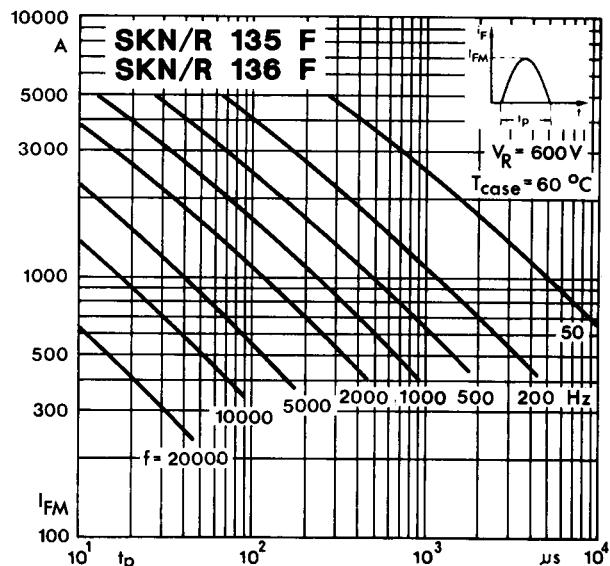


Fig. 1 a Rated sinusoidal peak forward current

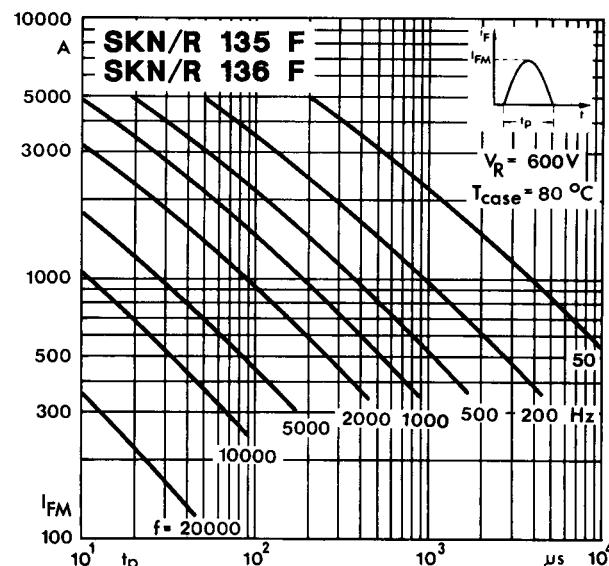


Fig. 1 b Rated sinusoidal peak forward current

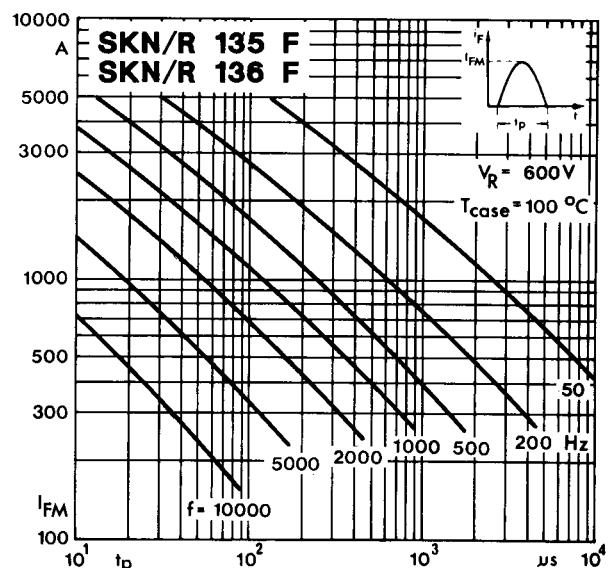


Fig. 1 c Rated sinusoidal peak forward current

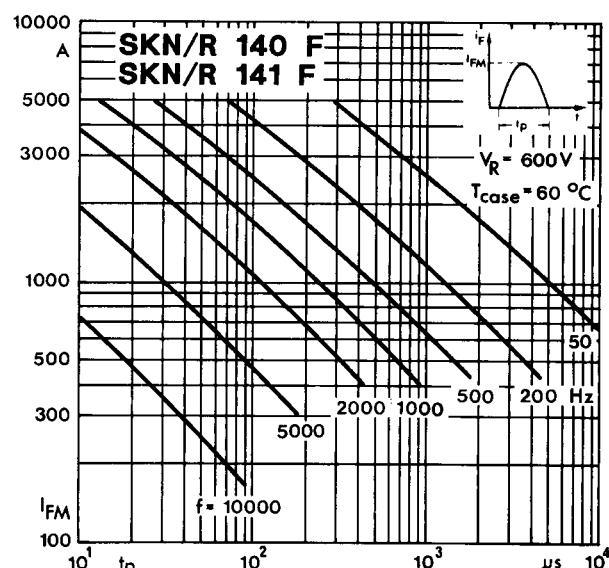


Fig. 1 d Rated sinusoidal peak forward current

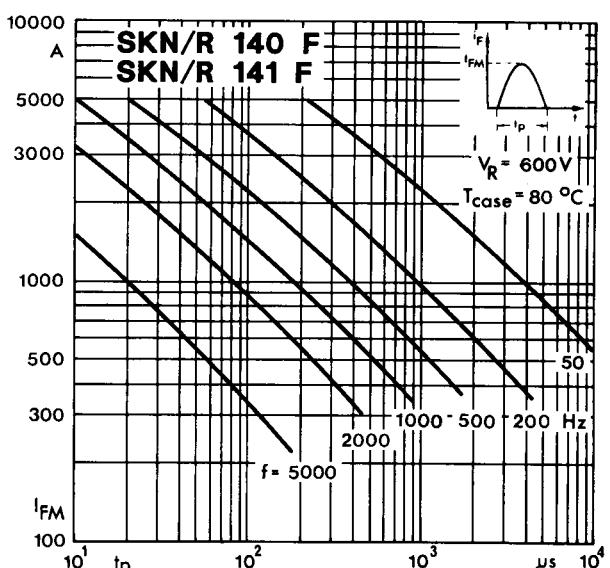


Fig. 1 e Rated sinusoidal peak forward current

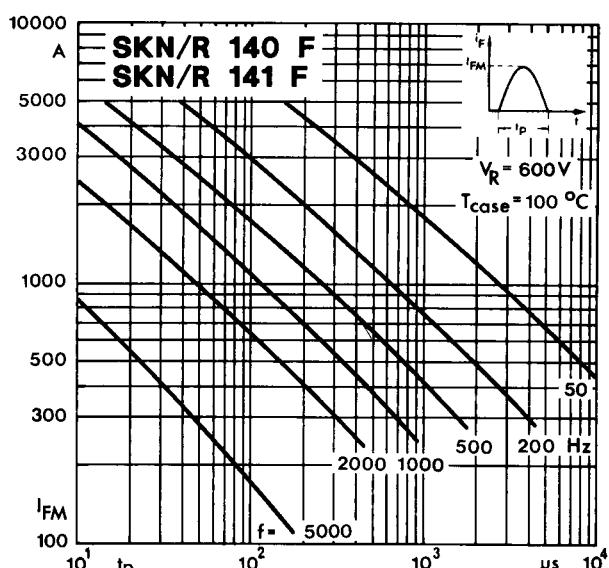


Fig. 1 f Rated sinusoidal peak forward current

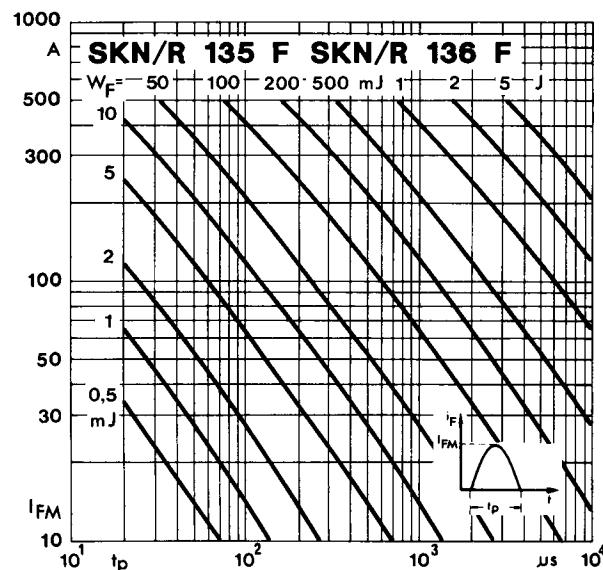


Fig. 2 a Forward energy dissipation, sinusoidal

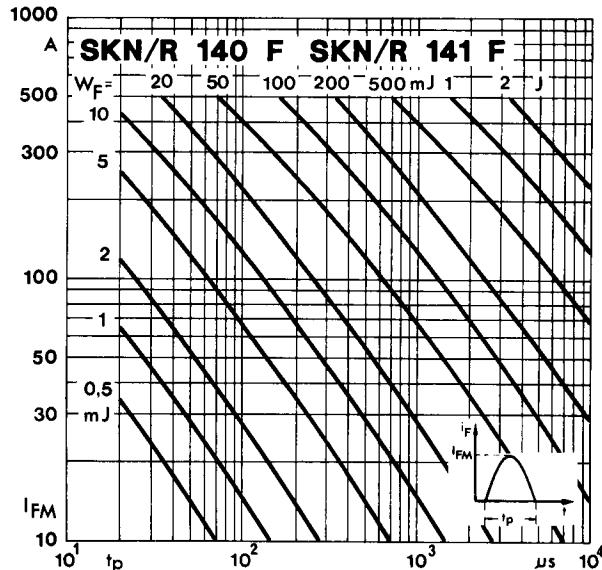


Fig. 2 b Forward energy dissipation, sinusoidal

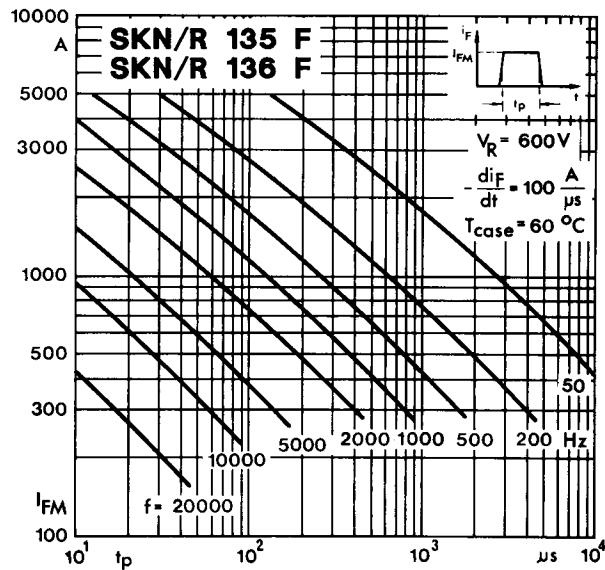


Fig. 3 a Rated rectangular peak forward current

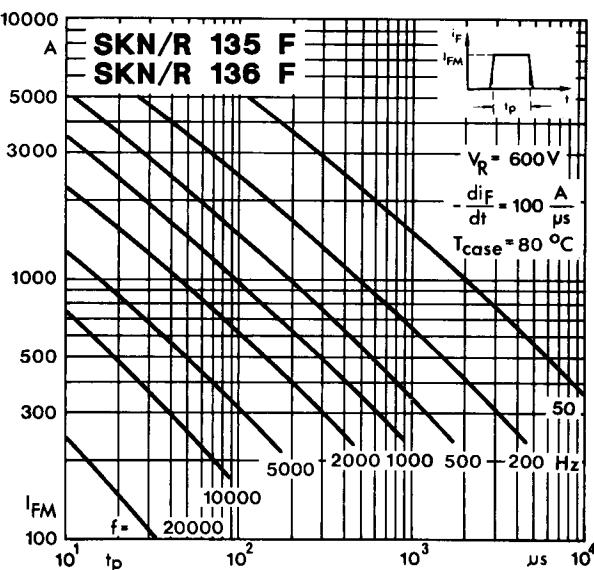


Fig. 3 b Rated rectangular peak forward current

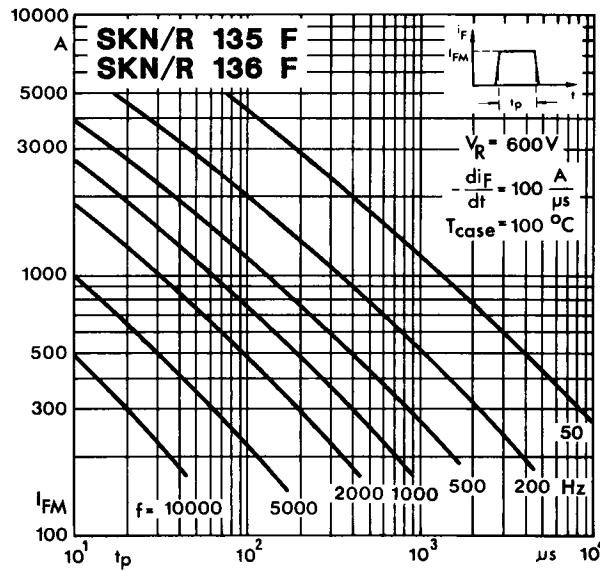


Fig. 3 c Rated rectangular peak forward current

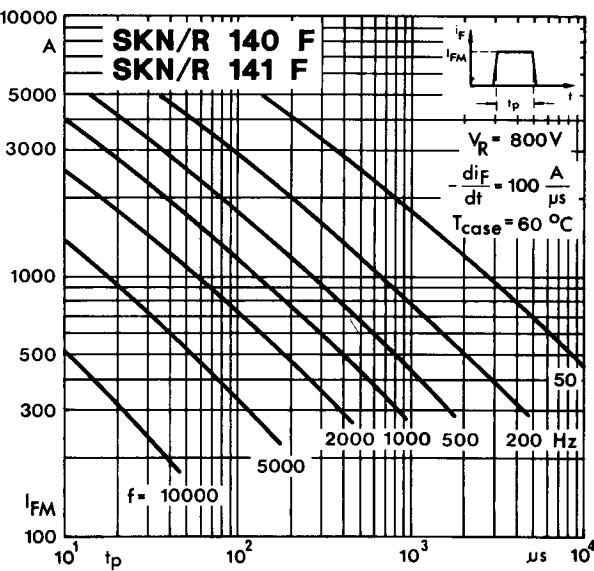


Fig. 3 d Rated rectangular peak forward current

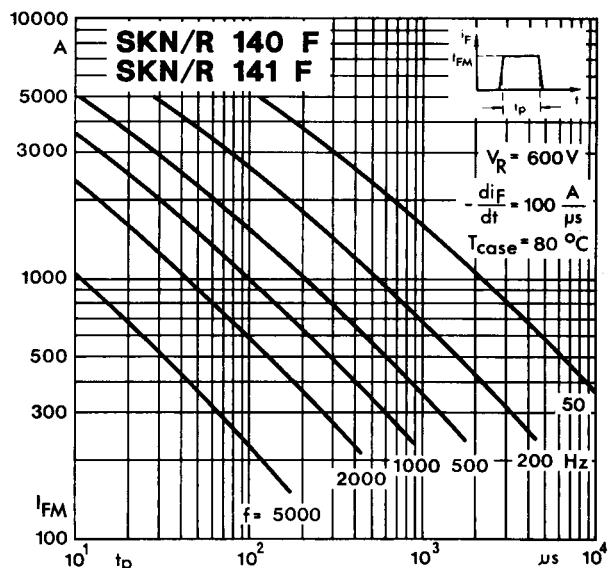


Fig. 3 e Rated rectangular peak forward current

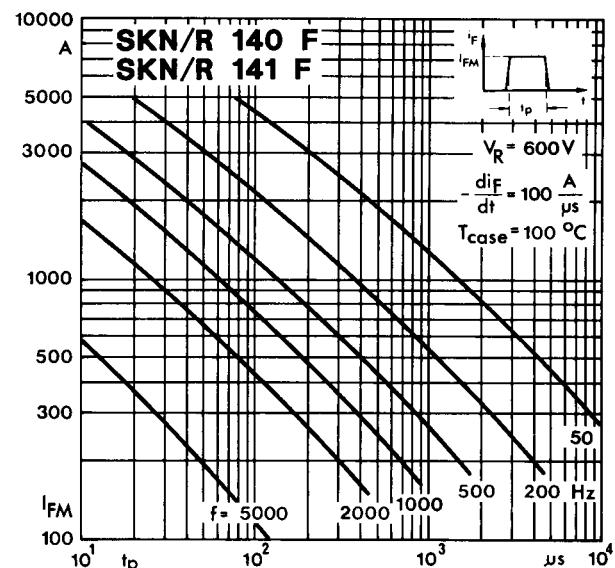


Fig. 3 f Rated rectangular peak forward current

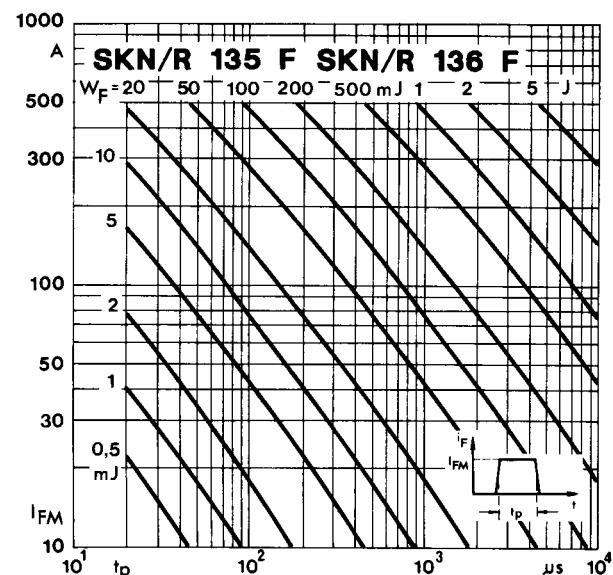


Fig. 4 a Forward energy dissipation, rectangular

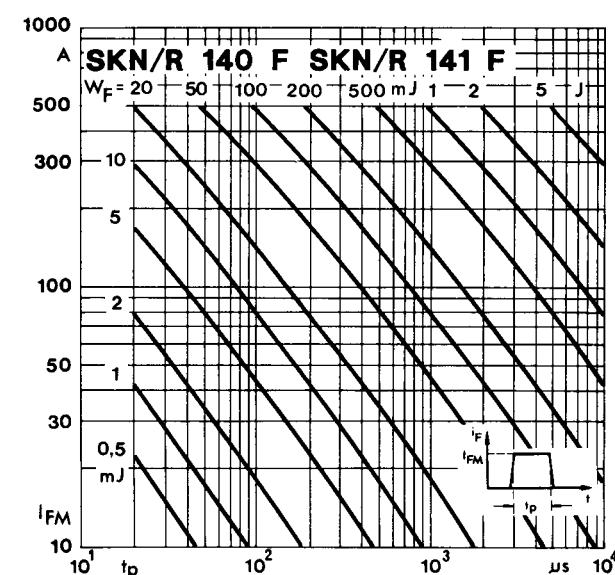


Fig. 4 b Forward energy dissipation, rectangular

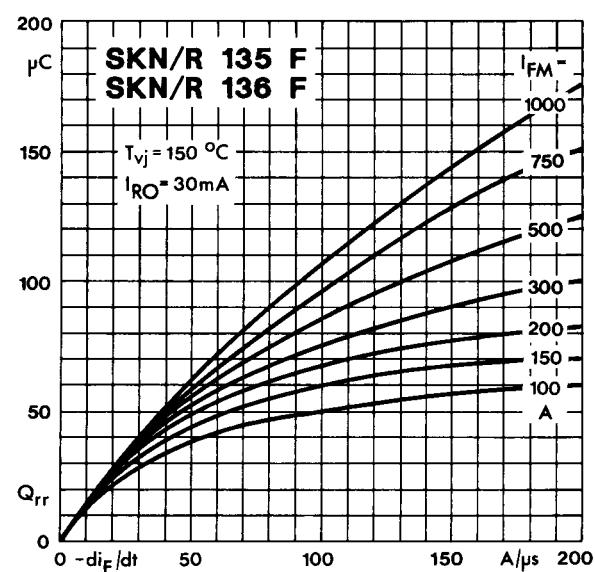


Fig. 5 a Recovered charge

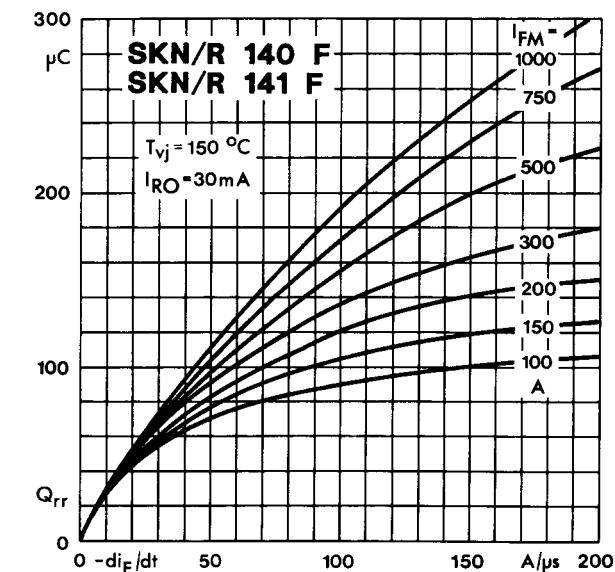


Fig. 5 b Recovered charge

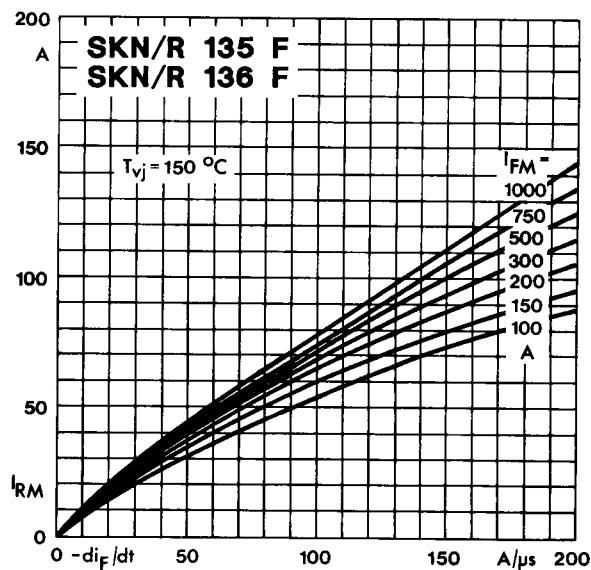


Fig. 6 a Peak reverse recovery current

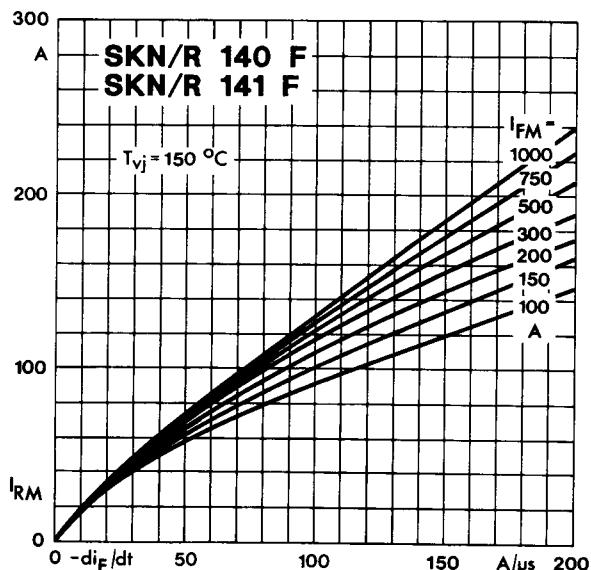


Fig. 6 b Peak reverse recovery current

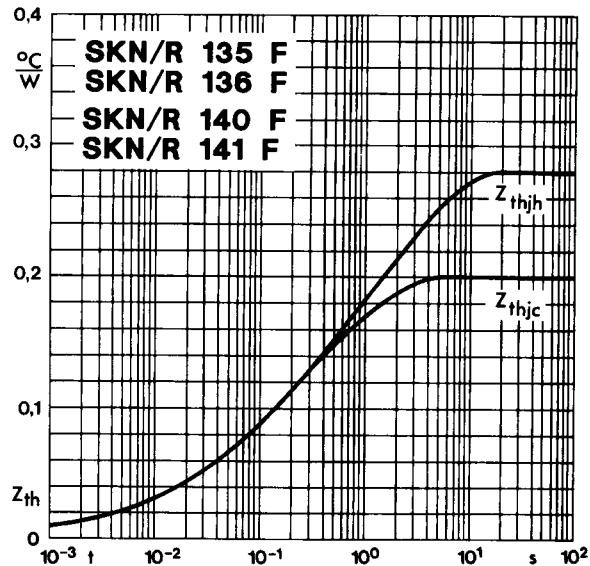


Fig. 7 Transient thermal impedance

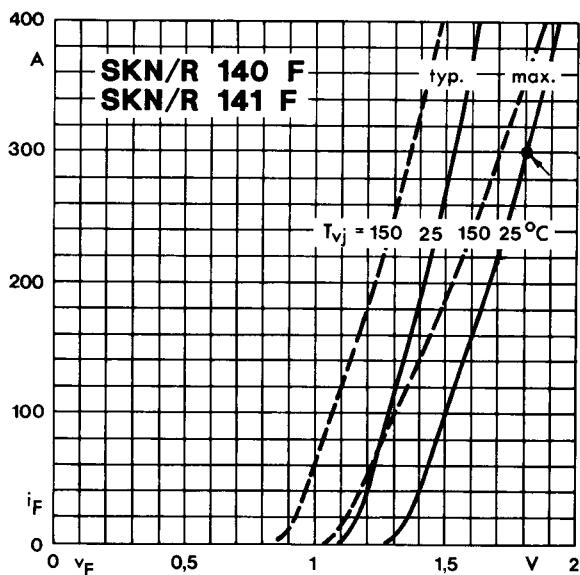


Fig. 8 b Forward characteristics

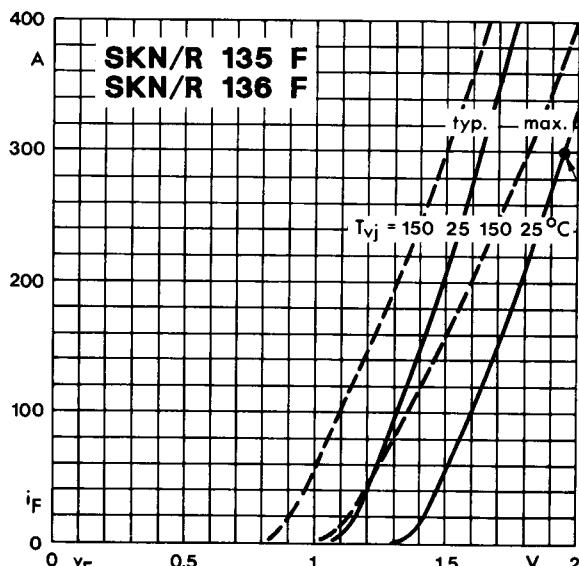


Fig. 8 a Forward characteristics

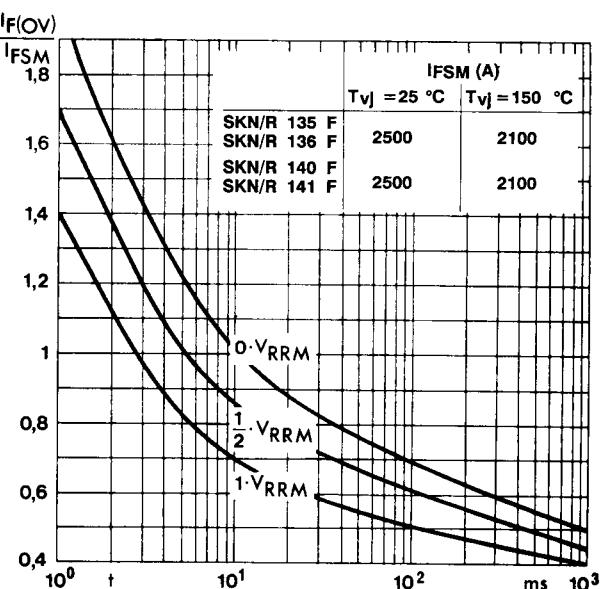
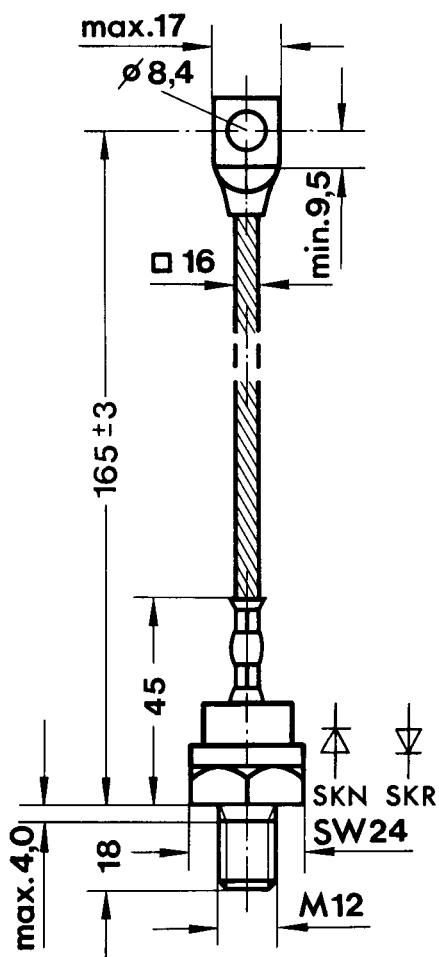


Fig. 9 Rated surge overload current

**SKN 135 F**  
**SKR 135 F**  
**SKN 140 F**  
**SKR 140 F**

Case E 14

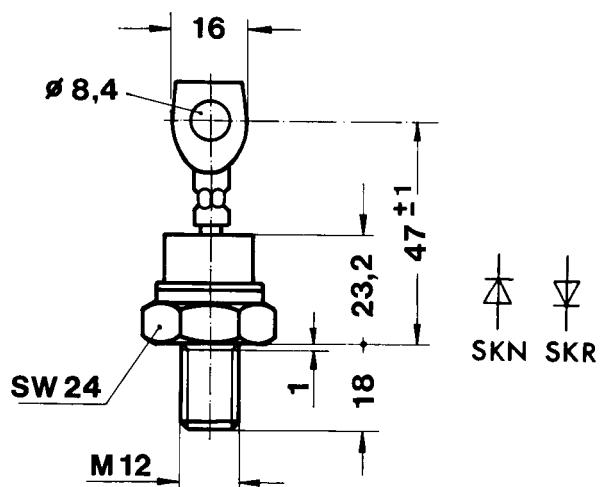
IEC: A 9 MA<sup>1)</sup>  
DIN 41 887: 105 B 2<sup>1)</sup>  
BS 3934: SO-29 B  
JEDEC: DO-205 AC (DO-30)<sup>1)2)</sup>



Dimensions in mm

**SKN 136 F**  
**SKR 136 F**  
**SKN 141 F**  
**SKR 141 F**

Case E 31



Dimensions in mm

<sup>1)</sup> modified

<sup>2)</sup> These types are also available with the original DO-205 AA (DO-8) dimensions with thread 3/8-24.